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TRANSMITTAL	Filing Date	07/07/2003				
FORM	First Named Inventor	Sreenivasan et al.				
(to be used for all correspondence after initial f.	īling) Art Unit	1732				
	Examiner Name	Unassigned				
Total Number of Pages in This Submission	Attorney Docket Number	P90/MII-51-33V50				
	ENCLOSURES (Check all that	t anniv)				
Fee Transmittal Form Fee Attached	Drawing(s) Licensing-related Papers	After Allowance communication to Technology Center (TC) Appeal Communication to Board of Appeals and Interferences				
Amendment/Reply After Final Affidavits/declaration(s) Extension of Time Request Express Abandonment Request Information Disclosure Statement	Petition Petition to Convert to a Provisional Application Power of Attorney, Revocation Change of Correspondence Addr Terminal Disclaimer Request for Refund CD, Number of CD(s)	Appeal Communication to TC (Appeal Notice, Brief, Reply Brief) Proprietary Information Status Letter Other Enclosure(s) (please Identify below): Form 1449 - IDS Forty-two (42) References Return Receipt Postcard to K. C. Brooks				
Certified Copy of Priority Document(s) Response to Missing Parts/ Incomplete Application Response to Missing Parts under 37 CFR 1.52 or 1.53	Remarks					
	TURE OF APPLICANT, ATTORN	EY, OR AGENT				
Firm Law Office of Kenneth C. E Individual name	Brooks					
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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: Sreenivasan et al. PATENT APPLICATION Serial No.: 10/614,716 Group Art Unit: 1732 Filing Date: July 7, 2003 Examiner: Unassigned

For: A CONFORMING TEMPLATE FOR PATTERNING LIQUIDS DISPOSED

ON SUBSTRATES

INFORMATION DISCLOSURE STATEMENT

Commissioner for Patents Alexandria, VA 22313

Sir:

The following information is submitted in compliance with Applicants' duty of disclosure under 37 C.F.R. § 1.56. Form PTO-1449 and a copy of each reference recited below accompanies this document. It is respectfully requested that the cited information be expressly considered during the prosecution of this application, and the references be made of record therein and appear among the "references cited" on any patent to issue therefrom.

ISSUED PATENTS

Patent Number 4,724,222	<u>Inventor</u> Feldman	<u>Grant Date</u> 02/09/1988
4,731,155	Napoli et al.	03/15/1988
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5,669,303	Maracas et al.	09/23/1997
5,772,905	Chou	06/30/1998
5,900,160	Whitesides et al.	05/04/1999
5,948,470	Harrison et al.	09/07/1999
6,039,897	Lochhead et al.	03/21/2000
6,309,580	Chou	10/30/2001
6,334,960	Willson et al.	01/01/2002
6,518,168	Clem et al.	02/11/2003

PENDING PATENT APPLICATIONS

<u>Serial Number</u> 09/698,317	<u>Inventor</u> Choi et al.	Filing Date 10/27/2000
09/907,512	Sreenivasan et al.	07/16/2001
09/908,455	Choi et al.	07/17/2001
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- Chou et al. "Imprint Lithography with Sub-10 nm Feature Size and High Throughput", Microelectronic Engineering 35, 1997, 237-240.
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- Scheer, H.C. et al. "Problems of Nanoimprinting Technique for Nanometer Scale Pattern Definition," Journal of Vacuum Science and Technology, 1998, 16, 3917-3921.
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Otto M. et al., "Step and Repeat UV-Nanoimprint Lithography: Material Issues," Nanoimprint and Nanoimprint Technology Conference, San Francisco, December 11-13, 2002.

Johnson et al., "Advances in Step and Flash Imprint Lithography, " SPIE Microlithography Conference, February 23-28, 2003.

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Alexandria VA (22)13. Signed: Why suffield Typed: Alexis Sheffield Date: March 11, 2004

Respectfully

Kenneth C. Brooks Reg. No. 38393

P.O. Box 10417

Austin, Texas 78766-1417 Telephone: 512-527-0104 Facsimile: 512-527-0107 patentsrus@earthlink.net

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Application Number	10/614,716			
Filing Date	07/07/03			
First Named Inventor	Sreenivasan et al.			
Group Art Unit	1732			
Examiner Name	Unassigned			
Attorney Docket Number	P90/MII-51-33V50			

		U.S. Patent Do	ocument	U.S. PATENT DOCUMEN	Date of Publication of	Pages, Columns, Lines,	
Examiner Initials*	Cite No.1	Number	Kind Code ² (if known)	Name of Patentee or Applicant of Cited Document	Cited Document MM-DD-YYYY	Where Relevant Passages or Relevant Figures Appear	
	A1	4,724,222		Feldman	02-09-1988		
	A2	4,731,155		Napoli et al.	03-15-1988		
	A3	5,425,848		Haisma et al.	06-20-1995		
	A4	5,669,303		Maracas et al.	09-23-1997	_	
	A5	5,772,905		Chou	06-30-1998		
	A6	5,900,160		Whitesides et al.	05-04-1999		
	A7	5,948,470		Harrison et al.	09-07-1999		
	A8	6,039,897		Lochhead et al.	03-21-2000		
	A9	6,309,580		Chou	10-30-2001		
	A10	6,334,960		Willson et al.	01-01-2002		
	A11	6,518,168		Clem et al.	02-11-2003		
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				FOREIGN	PATENT DOCUMENTS			
Examiner Initials*	Cite No.1	Cite No.1 Office Number (if known)		Kind Code ⁵	Name of Patentee or Applicant of Cited Document	Date of Publication of Cited Document MM-DD-YYYY	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	Т6
	A12	DE	2800476		Lamprecht et al.	07-13-1978		
	A13	JP	1-196749		Matsumoto et al.	08-08-1989		
	A14	wo	01/69317		Montelius et al.	09-20-2001		
	A15	wo	01/79592		Hallberg et al.	10-25-2001		
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Examiner Initials*	Cite, No.	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T ²
	A17	KRUG et al., "Fine Patterning of Thin Sol-Gel Films," Journal of Non-Crystalline Solids, 1992, pp. 447-450, vol. 147 & 148.	-
	A18	Krauss et al., "Fabrication of Nanodevices Using Sub-25nm Imprint Lithography," Appl. Phys. Lett 67(21), 3114-3116, 1995	
	A19	CHOU et al., "Imprint of Sub-25 nm Vias and Trenches in Polymers," Applied Physics Letters, November 20, 1995, pp. 3114-3116, vol. 67(21).	
	A20	CHOU et al., "Imprint Lithography with 25-Nanometer Resolution," Science, Apr. 5, 1996, pp. 85-87, vol. 272.	
	A21	HAISMA et al., "Mold-Assisted Nanolithography: A Process for Reliable Pattern Replication," Journal of Vacuum Science and Technology, Nov/Dec 1996, pp. 4124-4128, vol. B 14(6).	
	A22	CHOU et al., "Imprint Lithography with Sub-10nm Feature Size and High Throughput," Microelectronic Engineering, 1997, pp. 237-240, vol. 35.	
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	A28	Journal of the International Societies for Precision Engineering and Nanotechnology, 2001, pp. 192-199, vol. 25.	
	A29	CHOI et al., "High Precision Orientation Alignment and Gap Control Stages for Imprint Lithography Processes," U.S. Patent Application 09/698,317. Filed with USPTO on October 27, 2000.	
	A30	SREENIVASAN et al., "High-Resolution Overlay Alignment Methods and Systems for Imprint Lithography," U.S. Patent Application 09/907,512. Filed with USPTO on July 16, 2001.	
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	A37	OTTO M. et al., "Step and Repeat UV-Nanoimprint Lithography: Material Issues," Nanoimprint and Nanoprint Technology Conference, San Francisco, December 11-13, 2002.	
	A38	JOHNSON, et al., "Advances in Step and Flash Imprint Lithography, " SPIE Microlithography Conference, February 23-28, 2003.	

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INFORMATION DISCLOSURE				Filing Date	07/07/03	
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		CHOI et al., "A Chucking System and Method for Modulating Shapes of Subtrates," U.S. Patent Application	
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